Comparative study of film formation on high-purity Co and Stellite-6: Probing the roles of a chromium oxide layer and gamma-radiation

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Abstract
Gamma-irradiation significantly increases the corrosion potential on pure Co and the cobalt alloy, Stellite-6. To understand the radiation-induced corrosion of these materials, electrochemical studies of film formation and conversion on these metals were performed as a function of potential under both potentiodynamic and potentiostatic conditions. The oxidized surfaces were characterized by electrochemical impedance spectroscopy and X-ray photoelectron spectroscopy. Four characteristic potential regions are identified for anodic oxidation. Comparison of the behavior of pure cobalt and a cobalt alloy provides an insight into the role of an initial air-formed chromium oxide layer on the oxidation of Stellite-6 under different corrosion conditions.

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1. Introduction
Stellite-6 is a Co-based alloy with a complex metallurgical structure. Due to its high mechanical strength and corrosion resistance, this alloy is used in places that require high wear resistance, such as valve facings and ball bearings. These properties make Stellite-6 a significant alloy choice in nuclear power reactors. However, in a reactor core stable $^{59}$Co can absorb a neutron to become the radioactive isotope, $^{60}$Co. Thus, one of the operational and safety issues related to the use of cobalt-containing materials in a nuclear reactor is the potential formation of radioactive $^{60}$Co from $^{59}$Co released into the reactor core by corrosion. The $^{60}$Co created in this way constitutes a safety hazard for plant workers who have to perform maintenance on the reactor because the $^{60}$Co deposits on coolant circuit surfaces outside the reactor core [1].

Although Stellite-6 is known to be highly corrosion resistant under normal water conditions [1–3], its corrosion behavior in the presence of ionizing radiation has not been well established. Corrosion kinetics in water depend on both the aqueous redox conditions and the physical and chemical nature of the alloy surface. The high radiation fields present in a reactor core will cause water to decompose into a range of redox-active species (both highly oxidizing (e.g., $\text{OH}^-$, $\text{H}_2\text{O}_2^-$) and highly reducing (e.g., $\text{CO}_2^-$, $\text{O}_2^-$)). These species can significantly influence corrosion kinetics [4,5].

There are extensive corrosion studies reported for Co [6–12] and some Co-alloys [2,13,14]. However, there are fewer studies on Stellite-6 alloy in the literature [1,3]. Those corrosion studies have shown that a complex carbide network in the alloy matrix makes Stellite-6 resistant to wear, galling and corrosion, and that this resistance is retained at high temperatures (ca 300 °C) [1,3]. Systematic studies of Stellite-6 corrosion, and particularly in the presence of ionizing radiation are rare. The limited information on Stellite-6 corrosion mechanisms and kinetics as a function of aqueous conditions makes it difficult to assess the corrosion susceptibility of these alloys in the transient aqueous environments present in a reactor coolant system.

In this study, oxide formation and conversion on Stellite-6 in borate solution at pH 10.6 and room temperature were studied as a function of electrode potential under both potentiodynamic and potentiostatic conditions. The pH value is that maintained in the coolant water in CANDU® reactor coolant (pH measured at 25 °C) (a value chosen to minimize the corrosion of the carbon steel reactor components). It is an interesting choice for corrosion studies because the solubility of cobalt oxide species is at a minimum near this pH [11,15]. Consequently, oxide formation is preferred over metal dissolution during corrosion and, hence, oxide formation can be studied more easily. In support of our investigation of the corrosion behavior of Stellite-6, experiments on high purity cobalt were also carried out under the same conditions. Knowledge gained from the Co study aids in the interpretation of the anodic oxidation processes occurring on the Stellite-6 alloy. Various electrochemical methods, such as corrosion potential...
(ECORR) measurements, cyclic voltammetry, and electrochemical impedance spectroscopy (EIS) were used to study the corrosion kinetics, and the oxide films formed on the metals were further examined using scanning electron microscopy (SEM) and X-ray photoelectron spectroscopy (XPS).

2. Experimental

The two materials studied in this work are high-purity cobalt (99.95% purity and henceforth identified as Co) and Stellite-6 (Metals Samples Company). The alloy composition of Stellite-6 is presented in Table 1. Electrodes prepared from the metals had a flat, circular face, with a surface area of 10 mm² in the case of Stellite-6 and 12.5 mm² in the case of Co. Prior to each experiment the coupon surface was abraded manually with 400, 600, and then 1200 grit SiC papers, polished with 1 µm MetaDi Supreme diamond paste suspension (Buehler) on Texmet microcloth (Buehler), and then finally sonicated in an acetone/methanol mixture for 5 min to remove surface residues. The polished coupons were then sealed within multiple layers of polyolefin heat shrink tubing, leaving only the polished face exposed to the electrolyte solution. SEM images of as-prepared Co and Stellite-6 electrode surfaces are presented in Fig. 1. The Stellite-6 images show the presence of two distinct phases: a chromium-rich phase (dark areas) and a cobalt-rich phase (light areas).

2.1. Electrochemical cell

A three-electrode system consisting of a working electrode (the Co or Stellite-6 coupon), a reference electrode, and a counter electrode was used. A saturated calomel electrode (SCE, Fisher Scientific) was used as the reference electrode in all experiments except for the ECORR measurements in the gamma-irradiation cell. The gamma irradiation experiments employed a Hg/HgO reference electrode (Radiometer Analytical) in a 1.0 M KOH solution because this electrode has been shown to be more radiation-resistant than SCE or Ag/AgCl electrodes [16]. The Hg/HgO electrode has a potential of −0.131 V versus SCE. All potential values in this paper are quoted against the SCE scale to facilitate comparisons with our other work and other data reported in the literature.

Table 1

<table>
<thead>
<tr>
<th>W</th>
<th>Mn</th>
<th>Mo</th>
<th>Si</th>
<th>C</th>
<th>Ni</th>
<th>Fe</th>
<th>Cr</th>
<th>Co</th>
</tr>
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<tbody>
<tr>
<td>0.27</td>
<td>0.27</td>
<td>0.41</td>
<td>1.07</td>
<td>1.43</td>
<td>2.62</td>
<td>2.92</td>
<td>27.62</td>
<td>Bal.</td>
</tr>
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Fig. 1. SEM images of the surfaces of freshly prepared high-purity Co on the left hand panels and freshly prepared Stellite-6 on the right hand panels. Two magnification scales are used to show the degree of surface uniformity.

2.2. Solutions

All experiments were conducted at room temperature in Ar-sparged 0.01 M sodium borate solutions. The solutions were prepared using reagent grade Na₂B₄O₇ (Caledon Laboratories Ltd.) and water purified using a NANOpure Diamond UV ultra-pure water system (Barnstead International) with a resistivity of 18.2 MΩ cm. A pH of 10.6 was obtained by adding appropriate amounts of 1 M NaOH (Caledon Laboratories Ltd.) solution to the borate solution. The pH was measured prior to each experiment using an Accumet AB15 pH meter with standard size glass body combination electrode (Accumet 13-620-530).

2.3. Radiation source

All irradiation experiments were conducted in an MDS Nordion Gammacell 220 Excel Cobalt-60 irradiator. The electrochemical cell was positioned inside the gammacell sample chamber and the chamber was lowered into the irradiation zone, a cylindrical cavity surrounded by 11 tubular pencils containing 60Co. The absorbed radiation dose rate in the cavity during the period of experimentation was 5.5 kGy h⁻¹, where 1 Gy is equivalent to 1 J of energy absorbed per kg of water.

2.4. Procedure

A Solartron model 1480 multistat and a Solartron model 1255 frequency response analyzer were used in all electrochemical measurements. Corware™ and Zplot™ software (Scriber Associates) were used for experiment control, data acquisition and analysis. Electrochemical impedance spectroscopy (EIS) was performed by applying a sinusoidal potential stimulus of 10 mV amplitude on the DC bias potential used in the potentialistic polarization, over a frequency range of 10⁻³ to 10⁴ Hz.

Before each experiment the electrolyte solution was Ar-purged for at least 30 min. The freshly prepared working electrode was then cathodically cleaned at −1.1V_SCE for 5 min. For tests performed under each set of water conditions, a series of three electrochemical tests was performed on each material: (1) corrosion potential measurement, (2) cyclic voltammetry, and (3) potentiostatic polarization measurement. During the potentialistic polarization tests, the current response was monitored as a function of time and EIS spectra were periodically recorded. At the end of each potentialistic test, the electrode was removed from the cell, dried with Ar gas, and stored in a leak-tight vial. The electrode handling was performed in an Ar-purged glove box to minimize air oxidation and electrode contamination prior to surface analysis. Later the electrode was transferred in a sealed container and the electrode surface was analyzed by either SEM or XPS.

2.5. Surface analyses

An Hitachi S-4500 field emission SEM, operating in high-resolution mode, was used to examine the morphology of corrosion product deposits. X-ray photoelectron spectra were acquired on a KRATOS Axis Nova spectrometer using monochromatic Al Kα radiation and operating at 210 W, with a base pressure of 10⁻⁸ Pa. Under normal analysis conditions, the analysis spot size was approximately 400 × 700 µm. All spectra were calibrated with respect to the C 1s band (from adventitious carbon) whose energy was set to 284.8 eV [17]. Broad-spectrum survey scans were recorded at a pass energy of 160 eV to verify surface composition and cleanliness. High-resolution spectra (20 eV pass energy) were used to examine the Co 2p (binding energy, BE, at ∼780 eV), Cr 2p (∼574 eV), O 1s (∼530 eV), and C 1s (∼285 eV) bands [17].
3. Results and discussion

3.1. Corrosion potentials under gamma-irradiation

Fig. 2 shows the effect of gamma-irradiation on the $E_{\text{CORR}}$ of the Co and Stellite-6 electrodes. In the absence of radiation, the $E_{\text{CORR}}$ of both materials is established quickly (in ~20 min) and this value then trends very slowly and steadily upward, increasing from ~0.7 $V_{\text{SCE}}$ to ~0.6 $V_{\text{SCE}}$ over 50 h on the Co electrode and a similar increase is observed for Stellite-6, but with $E_{\text{CORR}}$ about 0.12 V more positive. When the corroding system is exposed to gamma-radiation, $E_{\text{CORR}}$ reaches different, higher values (increasing from ~0.7 $V_{\text{SCE}}$ to 0.08 $V_{\text{SCE}}$ for Co and increasing from ~0.48 $V_{\text{SCE}}$ to 0.12 $V_{\text{SCE}}$ for Stellite-6). It takes longer to reach the higher steady-state values (~1 h for Stellite-6 and ~3 h for Co), but, once reached, the $E_{\text{CORR}}$ values remained constant with time.

Corrosion of a metal in water involves oxidation of metal species coupled with reduction of aqueous species. This process depends on the electric field potential at the metal (or alloy) and water interface. When no external voltage is applied to the metal, the net rates of oxidation and reduction must be equal to maintain charge balance. The potential on the corroding surface at which this balance occurs is defined as the corrosion potential, $E_{\text{CORR}}$. The rate of metal oxidation depends on the potential difference between $E_{\text{CORR}}$ and the equilibrium potential of the metal redox reaction. Since the corrosion potential is a function of both anodic and cathodic reaction rates, changes in aqueous redox environment as well as changes in the oxide film can change the corrosion potential.

When exposed to ionizing radiation a small fraction of water decomposes to create a range of redox active species (gamma radiation absorbed directly by a metal coupon dissipates as heat). This is the reason for the change in $E_{\text{CORR}}$ shown in Fig. 2.

The impact of ionizing radiation on $E_{\text{CORR}}$ for Co and Stellite-6 is consistent with the observations of this impact on other alloys. Gamma-irradiation has been shown to increase $E_{\text{CORR}}$ from ~0.65 ± 0.05 $V_{\text{SCE}}$ on carbon steel [18] and $E_{\text{CORR}}$ from ~0.4 ± 0.1 $V_{\text{SCE}}$ to ~0.05 ± 0.05 $V_{\text{SCE}}$ on stainless steel [19], at pH 10.6 and room temperature. Previous studies on carbon steel [16,18,20] have shown that gamma-irradiation affects the corrosion process primarily by producing redox active species (such as $H_2O_2$) in the aqueous phase.

Oxide formation and conversion on Co and Stellite-6 were investigated as a function of potential under potentiodynamic (using cyclic voltammetry) and potentiostatic conditions over a potential range that encompasses the $E_{\text{CORR}}$ values observed in the absence and presence of radiation.

3.2. Oxide formation and conversion under potentiodynamic conditions

3.2.1. Assignments of the current peaks in cyclic voltammograms

Cyclic voltammetry (CV) was performed to establish characteristic potential ranges for the oxides that can be formed on Co and Stellite-6 under potentiodynamic conditions. The growth rate of the oxide layer in each potential region, as defined in this CV study, was then investigated in detail under potentiostatic conditions, see Section 3.3. To aid in the assignment of the current peaks seen in the cyclic voltammograms, the thermodynamic equilibrium potentials ($E^{\theta}$) for the redox reactions of cobalt and chromium species at pH 10.6 were calculated from reported standard potentials for the species [21]. These potentials are shown using vertical lines in Fig. 3. In addition to thermodynamic constraints, reaction kinetics can control oxide formation. Since the potential scan rate can alter the time available for a given reaction, differences observed in potentiodynamic and potentiostatic studies provide information on the role of kinetics on oxide formation. Although we acquired CVs as a function of a number of parameters (electrode rotation rate, potential scan rate and pH), only key results are present here.

3.2.1.1. High-purity Co. Cyclic voltammograms recorded on a Co electrode are shown in Fig. 4. The overlapping anodic peaks labeled A1 (~0.7 to ~0.6 $V_{\text{SCE}}$) and A2 (~0.5 $V_{\text{SCE}}$) can both be attributed to the oxidation of Co–CoII oxide/hydroxide (CoO/Co(OH)$_2$). There are two pathways for the oxidation of Co–CoII. Peak A1 lies below the $E_{\text{eq}}$ for the oxidation of Co in the bulk metal to Co(OH)$_2$ and is assigned to an oxidation process involving Co in a few surface monolayers:

![Fig. 3. Calculated equilibrium potentials for various redox reactions (at pH 10.6 and 25 °C) are indicated by vertical lines.](image)

![Fig. 4. Cyclic voltammograms obtained on Co. The CVs were recorded at a scan rate of 5 mV s$^{-1}$.](image)
A1: \[ \text{Co}_{\text{surf}} + 2(\text{OH})^{-}_{\text{ads}} \rightarrow [\text{Co(OH)}_{\text{ads}} + \text{OH}^- + \text{e}^-] \]
\[ \rightarrow \text{Co(OH)}_2(\text{or Co(OH)}_2^+) + 2\text{e}^- \]  
(1)

Peak A2 appears at potentials higher than the E_eq and it is assigned to the process:

A2: \[ \text{Co}_{\text{bulk}} + 2\text{OH}^- \rightarrow \text{Co(OH)}_2(\text{or Co(OH)}_2) + 2\text{e}^- \]  
(2)

The Co\(^{\text{II}}\) species at, or very near, the metal surface will be hydrated. The hydrated Co\(^{\text{II}}\) is in acid-base equilibrium with hydroxides:

\[ \text{Co(OH)}_2 + \text{OH}^- \rightarrow \text{Co(OH)}_2^- + \text{OH}^- \]  
(3a)

\[ \text{Co(OH)}_2 + 2\text{OH}^- \rightarrow \text{Co(OH)}_3^- + \text{OH}^- \rightarrow \text{Co(OH)}_4^{2-} \]  
(3b)

The hydrated species can dissolve from the metal/oxide interface where they can diffuse into the aqueous phase or precipitate (and/or condense) back onto the metal to form a solid Co(OH)/Co(OH)_2 film. Once a solid phase film is formed, reaction (2) may continue by the injection of Co\(^{\text{II}}\) into the oxide phase at the metal/oxide interface. This is balanced by injection of OH\(^-\) (or O\(^{2-}\)) into the oxide phase at the oxide/water interface.

Peak A2 is located at a higher potential because there is a slight barrier to overcome to oxidize the Co atoms in the bulk metal. This barrier is independent of the oxide surface state and we observe that the magnitude of peak A2 is independent of the number of CVs that have been performed on a sample. On the other hand, the magnitude of peak A1 increases with scan-cycle number. This behavior can be attributed to a process associated with Co at the metal surface where the reactive surface area and number of reactive sites are modified by the potential history of a metal.

The growth of the Co\(^{\text{II}}\) oxide/hydroxide layer passivates the surface and the current decreases. At potentials above 0.1 V_{\text{SCE}}, where the oxidation of Co\(^{\text{II}}\) to either Co\(^{\text{III}}\) or CoOOH is thermodynamically allowed (Fig. 3), the current increases again. The anodic barrier is independent of the oxide surface state and we observe an increased cycling and its corresponding reduction peak, C1, showed near reversible behavior. Peak A5 is assigned to the conversion of the Co\(^{\text{III}}\) oxide (Co\(_2\)O\(_3\)) to a Co\(^{\text{II}}\) oxide (Co\(_3\)O\(_4\)):

A5: \[ \text{Co}_2\text{O}_3 + \text{OH}^- \rightarrow \text{Co}_3\text{O}_4 + \text{H}_2\text{O} + \text{e}^- \]  
(6)

The reduction peaks C1 and C2 are assigned to reactions (7) and (8), respectively:

C1: \[ \text{Co}_3\text{O}_4 + \text{H}_2\text{O} + \text{e}^- \rightarrow \text{Co}_2\text{O}_3 + \text{OH}^- \]  
(7)

C2: \[ \text{Co}_3\text{O}_4 + \text{H}_2\text{O} + \text{e}^- \rightarrow \text{CoOOH} + \text{OH}^- \]  
(8)

The near reversibility of peaks A5 and C1 suggests that kinetically facile oxidation and reduction of Co\(^{\text{II}}\) and Co\(^{\text{III}}\) is occurring in the oxide lattice. Crystalline Co\(_2\)O\(_3\) has a normal spinel structure with Co\(^{\text{III}}\) occupying the octahedral sites and Co\(^{\text{II}}\) the tetrahedral sites [8]. Although the structure of the meta-stable Co\(_2\)O\(_3\) is less well established, anodic oxidation in a spinel oxide is known to occur easily [22] due to its spacious lattice structure: Co\(_2\)O\(_3\) is a p-type semiconductor with a small band gap in the range of 1.4–1.8 eV [8]. Similar reversible oxidation/reduction behavior has been observed for the conversion between Fe\(_2\)O\(_3\) and γ-Fe\(_2\)O\(_3\), both of which share a spinel structure (inverse spinel for magnetite) [22]. The broadening of peaks A5 and C1 with increasing scan-cycle number can be attributed to an increase in the reactive surface sites as the cycling increases.

Peak C3 was observed only when the upper scan limit of a CV was higher than 0.1 V_{\text{SCE}} and, hence, the assignment of this peak to the reduction of Co\(^{\text{III}}\) species is ruled out. Rather, this peak is assigned to the reduction of CoOOH to Co\(_2\)O\(_3\):

C3: \[ \text{CoOOH} + \text{H}_2\text{O} + \text{e}^- \rightarrow \text{Co(OH)}_2 + \text{OH}^- \]  
(9)

This assignment is consistent with the study by Behl et al. [9] which showed that the oxidation of Co\(_2\)O\(_3\) to CoOOH occurs readily, but the reduction of CoOOH to Co\(_3\)O\(_4\) is very slow.

In summary, the CV results show three potential regions of anodic oxidation of Co at pH 10.6:

Region I (0 < 0.7 V_{\text{SCE}}): This region lies below the equilibrium potential for the Co to CoOOH/CoOOH\(_2\) reaction and no bulk Co oxidation is observed (or expected) in this region.

Region II (0.7 < E < 0.1 V_{\text{SCE}}): Oxidation of Co in the bulk metal phase is limited to the formation of CoOOH/CoOOH\(_2\).

Region III (E > 0.1 V_{\text{SCE}}): Oxidation of Co to Co\(^{\text{III}}\) oxide/hydroxide continues but the Co\(^{\text{II}}\) formed is also further oxidized to less soluble Co\(^{\text{IV}}\) and/or Co\(^{\text{II}}\) oxides/hydroxides.

The division of the oxidation processes into three potential regions is in good agreement with previous studies on Co in a mildly basic solution (pH range of 9.3–12) [6,10,11]. Those studies also concluded that two types of passive layers are formed in alkaline solutions: a layer formed at low potentials that consists of CO and a layer formed at high potentials that consists of CoOOH and Co\(_2\)O\(_3\) on top of an inner layer of CoO [6,10].

The corrosion potential of Co without ionizing radiation present is measured at ~0.7 V_{\text{SCE}} to ~0.6 V_{\text{SCE}} (Fig. 2), a value at or slightly higher than the transition potential between regions I and II (i.e., the equilibrium potential for the Co to CoOOH/CoOOH\(_2\) reaction). In contrast, E_{\text{corr}} with 5.5 kGy h\(^{-1}\) ionizing radiation present (0.08 V_{\text{SCE}}, Fig. 2) is at the transition between regions II and III.
3.2.1.2. Stellite-6. Cyclic voltammograms recorded on Stellite-6 are shown in Fig. 5; two different scan ranges were used. –1.1 \( V_{\text{SCE}} \) to 0.1 \( V_{\text{SCE}} \) and –1.1 \( V_{\text{SCE}} \) to 0.6 \( V_{\text{SCE}} \). Also shown in Fig. 5a is the first cycle of a CV performed on Co for comparison. The first anodic peak (labeled A1(St-6) for Stellite-6) in Fig. 5a appears at a much lower potential than the first peak seen on Co (A2(Co)). At this potential, Co oxidation to Co\(^{3+}\) oxide/hydroxide is not thermodynamically allowed potentials. However, the equilibrium potentials for the oxidation of Cr to Cr\(^{3+}\) (CrOOH and Cr\(_2\)O\(_3\)) lie below –1.4 \( V_{\text{SCE}} \). The Stellite-6 surface is initially covered by a thin, air-formed Cr\(^{3+}\) oxide and this oxide is not completely removed during the electrocathodic treatment before the first CV. Peak A1(St-6) can therefore be attributed to the oxidative injection of Co\(^{2+}\) into the chromium oxide layer, leading to conversion of that layer to cobalt chromite, CoCr\(_2\)O\(_4\). This is followed by formation of a Co\(^{3+}\) oxide/hydroxide outer layer at higher potentials:

\[
\text{A1(St-6)}: \text{Co} + 2\text{OH}^- + \text{Cr}_2\text{O}_3 \rightarrow \text{CoCr}_2\text{O}_4 + \text{H}_2\text{O} + 2\text{e}^- \tag{10}
\]

Chromium oxide, Cr\(_2\)O\(_3\), being a p-type semi-conductor with a large band gap of 3.4 eV [23], is ionically insulating at low potentials and, therefore, its presence should significantly impede the further oxidation of an underlying metal. However, the air-formed chromium oxide is likely defective, and the Co\(^{2+}\) ion is thermodynamically stable in a chromium oxide layer when the oxide layer is not thermodynamically stable in a chromium oxide layer. When the Cr\(^{3+}\) oxide layer is saturated with Co\(^{2+}\) and a potential greater than –0.7 \( V_{\text{SCE}} \) is applied, additional Co\(^{2+}\) can migrate through the oxide layer to the chromite/water interface where it can be hydrated and subsequently condense to grow an outer layer of CoO/Co(OH)\(_2\) or diffuse into the aqueous phase. Consequently, we see the presence of both CoCr\(_2\)O\(_4\) and CoO/Co(OH)\(_2\) in an oxide potential–stastically grown at –0.7 \( V_{\text{SCE}} \) (see XPS results below).

The presence of a CoCr\(_2\)O\(_4\) layer adds a barrier to cation migration that is not present in pure Co and this explains why the electrochemical reactivity of the Stellite-6 surface is much lower than that of the Co surface (lower anodic current densities) at potentials > –0.6 \( V_{\text{SCE}} \) (see further discussion below).

With an upper scan limit of 0.1 \( V_{\text{SCE}} \), the onset of peak A1(St-6) appears at a lower potential in the first cycle than in subsequent cycles (Fig. 5a). Stable Cr\(_2\)O\(_3\) has a corundum crystal structure while stable CoCr\(_2\)O\(_4\) has a spinel structure [24]. Injection of Co into the Cr\(_2\)O\(_3\) oxide lattice requires energy sufficient to induce the required changes to the oxide lattice structure. When the upper limit of the potential scan is increased to 0.6 \( V_{\text{SCE}} \), the anodic current density seen near –0.7 \( V_{\text{SCE}} \) is much reduced in the second and higher number of CV cycles compared to that of the first cycle (Fig. 5b). This is because of changes to the chromium oxide that occur at higher potentials. At potentials >0.3 \( V_{\text{SCE}} \), Cr\(^{3+}\) can oxidize to Cr\(^{6+}\) which can readily dissolve in water. This dissolution removes the chromite layer. A more coherent and compact Cr\(_2\)O\(_3\) oxide layer than the initial defective layer forms after the first CV cycle and this more insulating layer inhibits Co\(^{2+}\) migration. Consequently, the Stellite-6 CVs cycles over the potential range –1.1 to 0.6 \( V_{\text{SCE}} \) are very different for cycle 1 and subsequent CV cycles, and the latter do not show any further anodic current at low potentials.

The CV of Stellite-6 in Fig. 5b shows that the anodic current increases again at potentials above –0.6 \( V_{\text{SCE}} \) (first cycle) and above 0.2 \( V_{\text{SCE}} \) for subsequent cycles. In the potential range –0.6 \( V_{\text{SCE}} \) to 0.1 \( V_{\text{SCE}} \), the growth of the outer CoO/Co(OH)\(_2\) layer continues. The anodic current in this region increases nearly linearly with potential during the scan and this is attributed to a linear growth in the thickness of the outer CoO/Co(OH)\(_2\) layer. The impact of the increasing potential is balanced by a commensurate increase in the ohmic resistance of the oxide layer as it thickens. As the potential is scanned above –0.2 \( V_{\text{SCE}} \), the current stays nearly constant with potential and this behavior is attributed to control of the reaction rate by diffusion of OH\(^-\) to the surface. No anodic current is seen in this potential region for scan cycles greater than 1 because of the presence of the insulating Cr\(_2\)O\(_3\) oxide layer.

Since electrode potentials in the range 0.1 and 0.2 \( V_{\text{SCE}} \) are not high enough to support anodic dissolution of chromium (by oxidizing insoluble Cr\(^{3+}\) to soluble Cr\(^{6+}\)) [25], the anodic current in this potential range is due to the oxidation of cobalt species, see reactions (4), (5) and (6). The rates of these reactions are much slower on Stellite-6 than on Co due to the presence of the cobalt chromite inner layer.

At potentials above 0.3 \( V_{\text{SCE}} \), where Cr\(^{3+}\) can be easily oxidized to highly soluble Cr\(^{6+}\) oxides, the anodic current increases rapidly with potential. In this high potential region, the oxidative dissolution of chromium dominates the anodic current behavior. On the return CV sweep, the reduction current begins to flow almost immediately and is distributed over a very wide potential range, down to about –0.3 \( V_{\text{SCE}} \) (peak C1(St-6)). The broad cathodic feature, labeled C(St-6) in Fig. 5b, probably comprises the processes included in both peaks C1 and C2 on Co (Fig. 4), but the separation into two peaks is lost, perhaps due to the influence of chromium oxides on the film conversion kinetics [13] and also the reduction of any Cr\(^{6+}\) species that were still retained with the film at the end of anodic CV sweep.

In summary, the CV results for Stellite-6 show that oxidation behavior can be divided into four potential regions at pH 10.6. These regions are almost identical to the regions identified for Co oxidation (with the differences in the transition between Region I...
and Region II matching the differences in the values of $E_{\text{CORR}}$ for the metals. Stellite-6 has an extra region at high potentials to account for Cr oxidation.

Region I ($E < -0.6 \text{ V}_{\text{SCE}}$): In this region the oxidation of Co to Co$^{II}$ converts the pre-existing chromium oxide layer to cobalt chromite.

Region II ($-0.6 \text{ V}_{\text{SCE}} < E < 0.1 \text{ V}_{\text{SCE}}$): The oxidation of Co to Co$^{II}$ continues. When the chromite layer becomes saturated with Co$^{II}$, CoO/(Co(OH)$_2$ is formed at the oxide/water interface. The rate of anodic oxidation in this region is much lower on Stellite-6 than on Co.

Region III (0.1 $\text{ V}_{\text{SCE}} < E < 0.3 \text{ V}_{\text{SCE}}$): In this region Co$^{II}$ oxide/hydroxide is continuously formed and it is also further oxidized to less soluble Co$^{III}$ and/or Co$^{III}$ oxides/hydroxides.

Region IV ($E > 0.3 \text{ V}_{\text{SCE}}$): The oxidative dissolution of chromium becomes the dominant anodic process.

Like the cobalt system, $E_{\text{CORR}}$ of Stellite-6 without ionizing radiation present is about $-0.47 \text{ V}_{\text{SCE}}$, a value slightly higher than the transition between regions I and II, whereas with ionizing radiation present $E_{\text{CORR}}$ is about 0.12 $\text{ V}_{\text{SCE}}$, a value at the transition potential between regions II and III.

3.3. Oxide formation and conversion under potentiostatic conditions

3.3.1. Experimental results and data analyses

Oxide formation was studied under potentiostatic conditions at three potentials, −0.7, −0.2 and 0.2 $\text{ V}_{\text{SCE}}$ for both Co and Stellite-6. These potentials were chosen based on the electrochemical reactivity seen in CV scans. Additional potentiostatic experiments were carried out on Stellite-6 at a number of applied potentials in the range from 0.1 $\text{ V}_{\text{SCE}}$ to 0.4 $\text{ V}_{\text{SCE}}$. In the potentiostatic experiments, a desired potential, $E_{\text{APS}}$, was applied immediately after cathodically stripping the electrode at $-1.1 \text{ V}_{\text{SCE}}$ for 5 min. The current was monitored as a function of time (typically up to 2 d) to obtain kinetic information on anodic oxidation processes occurring on the Co and Stellite-6 surfaces. Electrochemical impedance spectra (EIS) were recorded periodically during a potentiostatic test to characterize the oxide films that were formed. Upon the conclusion of each experiment, the electrode was removed from the electrochemical cell and the surface was characterized using XPS. The XPS analysis provides information on the state of the metal surface after extended oxidation and the current vs. time plots and EIS spectra provide information on the film growth kinetics. The EIS spectra were modeled using electric equivalent circuits to derive the resistance and capacitance of the electrochemical systems. The XPS spectra were deconvoluted using standard reference spectra to determine the chemical composition and oxidation states of the metal atoms in the oxide layers.

The results of EIS measurements and analyses are discussed first because this aids in discussion of the other results. Representative EIS spectra, recorded on Stellite-6 during polarization at 0.2 $\text{ V}_{\text{SCE}}$, are shown in a Bode plot in Fig. 6a. The EIS spectra obtained during potentiostatic polarization at $-0.2 \text{ V}_{\text{SCE}}$ and 0.2 $\text{ V}_{\text{SCE}}$ were analyzed using a modified Randles electric equivalent circuit model to extract the capacitive and resistive characteristics of the films formed on the surfaces. An electric equivalent circuit analysis of the EIS obtained at $-0.7 \text{ V}_{\text{SCE}}$ was not performed due to the large water reduction currents observed for both Co and Stellite-6 surfaces at this potentials.

In our work, the Co and Stellite-6 surfaces contain several oxide phases that are not distinct and, hence, their individual RC components are not easily separated. Thus, a simple Randles-type circuit consisting of one RC (resistor–capacitor) component in series with the resistance of the solution, $R_s$, used to model the oxide layer as a whole. A constant phase element (CPE) was used in place of the capacitor for the EIS analysis. A more complex equivalent circuit model could be used but, since there is no unique solution to a least squares fit to our EIS data, this was not done. The Randles-type circuit provides a good fit to our EIS data, as shown in Fig. 6b. The CPE accounts for non-idealitys (i.e., frequency dispersion) in the capacitive response of the system. The exponent of the CPE, $\alpha$, derived from fitting this circuit model to the data, was in the range of 0.8–0.85, indicating that the electrode possessed a very capacitor-like interface (a value of 1 applies to a pure capacitor). The CPE parameters were converted to capacitance values using the method of Brug et al. [26]. The resistance and capacitance values obtained from fitting the EIS data are shown in Fig. 7. Although the polarization (or system) resistance, $R_p$, is theoretically composed of a film resistance, $R_{\text{film}}$, and an interfacial charge transfer resistance, $R_{\text{ct}}$, in series with one another, the equivalent circuit analysis of the EIS data could not resolve the contributions of $R_{\text{film}}$ and $R_p$ or those of different oxide films, so the additive polarization resistance $R_p$ is plotted in Fig. 7.

X-ray photoelectron spectroscopy (XPS) was used to characterize the chemical states of Cr and Co in the oxide films. Both low resolution (or survey) spectra and high resolution spectra in the Co 2p, Cr 2p, and O 1s regions were used. The ratio of Co to Cr in the Stellite-6 films was obtained from the relative areas of the Co 2p peak at 780 eV and the Cr 2p peak at 574 eV in the survey spectra. To determine the oxidation state(s) of Co atoms in a film, the high resolution spectra of the Co 2p band were deconvoluted using reference spectra for single-phase Co$^{II}$, Co(OH)$_2$, CoO, Co$_3$O$_4$, CoOOH, and CoCr$_2$O$_4$ (with binding energies of 778.1, 780.4, 780.6, 779.6, 780.1 and 778.8 eV, respectively) [17]. A representa-
3.3.2. High-purity Co

3.3.2.1. Film growth at \(-0.7 \text{ V}_{\text{SCE}}\). The time dependent behavior of current as a function of time at constant potential is shown in the log |i| versus log |t| plot in Fig. 11a. During potentiostatic polarization at \(-0.7 \text{ V}_{\text{SCE}}\), the current initially decreases linearly with time (i.e., the slope of the log |i| vs. log |t| plot is \(-1\)) but switches in sign from anodic to cathodic at \(\sim 100 \text{ s}\) (Fig. 11a). The linear decrease in the anodic current within 100 s indicates that the nature of the oxide formed on Co does not change during this time. This is consistent with growth of a Co\textsuperscript{0} oxide/hydroxide layer at a constant rate at this potential (reaction 1). The solubility of Co(OH)\textsubscript{2} is at its minimum at pH 11 (\(\sim 1 \text{ M}\)) [11,15] and a uniform solid phase of Co\textsuperscript{0} oxide/hydroxide quickly covers the surface. The current density decreases steadily as the oxide thickens.

At \(\sim 100 \text{ s}\) the current becomes cathodic and its magnitude quickly reaches a steady-state value (constant for the rest of the potentiostatic experiment). Cobalt oxide/hydroxide is known to be electronically conducting [12]. Although it is a p-type semiconductor it has a small band gap of 2.4 eV and a photocurrent can be easily generated by room fluorescent lighting (the experiments were not conducted in the dark). The negative current is attributed to reduction of aqueous species on this electronically conducting surface, possibly driven a photo-process. This process is hidden to reduction of aqueous species on this electronically conducting surface, possibly driven a photo-process. This process is hidden.
limited tests in a darkened laboratory showed a reduction in the cathodic current level.

The XPS analysis of the film formed at −0.7 \(V_{	ext{SCE}}\) (Fig. 9a) shows a substantial contribution of a metal atom component (Co\(^{0}\)) to the Co 2p peak (−10%). This component comes from the bulk metal that underlies the surface oxide and indicates that the oxide film is less than 10 nm thick (the depth analysis range of the XPS instrument). The remaining contribution to the Co 2p band is from CoO/Co(OH)\(_2\). Analysis of the high resolution O 1s peak shows a high contribution from OH\(^{-}\) (Fig. 9b) indicating that Co\(^{0}\) is present mostly in the hydroxide form (Co(OH)\(_2\)).

### 3.3.2.2. Film growth at −0.2 \(V_{	ext{SCE}}\)

During potentiostatic polarization at −0.2 \(V_{	ext{SCE}}\), the current is initially high at ~3 mA cm\(^{-2}\) and remains nearly constant for a short duration (Fig. 11a). The current then drops abruptly and subsequently decreases linearly with time from this new, lower current level to reach a very low value of 60 nA cm\(^{-2}\) after ~10\(^5\) s (~1 d). At this potential the rate of Co to Co\(^{0}\) oxidation at the metal/water interface is initially very high due to large overpotential. The high short-term current can be attributed to the fact that the oxidation of Co to Co\(^{0}\) is limited not by the rate of interfacial charge transfer but by the diffusion of charged species (metal cations and aqueous ions, H\(^{+}\) and OH\(^{-}\)) through the Helmholtz or double layer (or the interfacial region). The rate of movement of charged species through the double layer depends on the electric field potential gradient across the layer. Injection of a large amount of Co\(^{0}\) can result in a significant IR drop across into the interfacial region and can slow down the diffusion of the charged species [28].

When the concentration of Co\(^{0}\) species in the interfacial region reaches its solubility limit, the Co\(^{0}\) species precipitate and condense into a solid phase oxide/hydroxide. With this solid film present, the oxidation rate is limited by the rates of interfacial charge transfer and/or ion transport through the oxide. Thus, the rapid formation of a uniform layer of Co\(^{0}\) oxide/hydroxide causes a sudden drop in the current.

Once a uniform coherent oxide layer is formed, the anodic oxidation rate of Co to Co\(^{0}\) is determined by the rate of interfacial charge transfer at the metal/oxide and oxide/water interfaces and the rate of Co ion migration through the oxide layer. The Co\(^{0}\) produced can either be incorporated into the growing oxide layer or be transported to the oxide/water interface where it can be hydrated and dissolve into the aqueous phase. The linear decrease in the anodic current with time suggests the current is mainly due to oxide growth and that the dissolution current is small. As the oxide layer thickens anodic oxidation slows and the anodic oxidation rate approaches the rate of dissolution of the Co cation from the oxide surface. The system eventually reaches a steady-state balance between the rates of Co oxidation and Co dissolution and the oxide layer no longer grows. As expected, at long times the anodic current is higher for the higher applied potential.

The current on an electrode during the linear decrease period was about an order of magnitude higher during polarization at −0.2 \(V_{	ext{SCE}}\) than that seen at −0.7 \(V_{	ext{SCE}}\) (Fig. 11a). This higher current...
can support the growth of a thicker film. This is consistent with the XPS results (Fig. 9a) which show the presence of a thicker Co\textsuperscript{II} oxide/hydroxide layer on an electrode treated at −0.2 V\textsubscript{SCE} compared to the layer on an electrode treated at −0.7 V\textsubscript{SCE}.

The equivalent electric circuit analysis of the EIS taken at −0.2 V\textsubscript{SCE} (Fig. 7) yielded a polarization resistance value that is relatively low (initially ~0.2 MΩ cm\textsuperscript{2} and increasing to a steady-state value of ~0.5 MΩ cm\textsuperscript{2} after 2 h). The increase in \(R_p\) is accompanied by a decrease in the system capacitance from ~4 F cm\textsuperscript{−2} to ~7 F cm\textsuperscript{−2}. The increase in resistance can be caused by either a thickening of an oxide film or the conversion of an existing film to a more insulating oxide. The increase in capacitance can be caused by either a decrease in film thickness, an increase in electrode surface area, or an increase in the dielectric constant of the oxide film. The XPS results (Fig. 9a) show that only CoO/Co(OH)\textsubscript{2} is present (within the analysis depth of 10 nm). The increase in resistance is attributed to the thickening of this oxide and the increase in capacitance is attributed to an increase in the active electrode surface area as the oxide grows. An SEM image of the surface (not presented) shows the presence of a filiform layer. This physical structure has an active surface area that is much larger than the geometric area of the electrode coupon. Growth of this type of structure is consistent with an increase in the active surface area of a CoO/Co(OH)\textsubscript{2} oxide layer.

3.3.2.3. Film growth at 0.2 V\textsubscript{SCE}. The current observed during polarization at 0.2 V\textsubscript{SCE} shows similar behavior to the current observed at −0.2 V\textsubscript{SCE} (Fig. 11a). The initial current is the same, but the duration of near constant current lasts longer at 0.2 V\textsubscript{SCE}. This short-term behavior is attributed to the same phenomena discussed above for the polarization at −0.2 V\textsubscript{SCE}. The current remains longer at a higher potential because the diffusion of charged species through the double layer will be prolonged by the higher potential gradient in the interfacial region. The larger current drop at 0.2 V\textsubscript{SCE} than at −0.2 V\textsubscript{SCE} is attributed to the formation of a thicker oxide at this potential as more Co\textsuperscript{II} species accumulate in the oxide layer over the longer cation diffusion length.

Following a sudden initial current drop, the current decreases linearly. Again, this is consistent with the growth of a thicker oxide layer. However, the current at 0.2 V\textsubscript{SCE} actually drops below the current seen at −0.2 V\textsubscript{SCE} for some time, but then the situation reverses after ~500 s. The XPS results (Fig. 9) show that the oxide layer formed at 0.2 V\textsubscript{SCE} the film consists of both Co\textsuperscript{II} oxide/hydroxide and CO\textsubscript{3}O\textsubscript{4} while the film formed at −0.2 V\textsubscript{SCE} consists of only CoO/Co(OH)\textsubscript{2}. We attribute the lower current at 0.2 V\textsubscript{SCE} at intermediate times to the early growth of a thicker oxide film. At longer times the current at 0.2 V\textsubscript{SCE} becomes greater than that at −0.2 V\textsubscript{SCE} as the oxidation of Co\textsuperscript{II} to CoO/Co\textsubscript{3}O\textsubscript{4} contributes more to the total current. The Co 2p band in the XPS spectra were successfully deconvoluted without any contribution from Co\textsubscript{3}O\textsubscript{4}. The reference spectrum of this oxide was not available and, hence, it was not included in the XPS deconvolution. The oxidation of CO\textsubscript{3}O\textsubscript{4} to CO\textsubscript{3}O\textsubscript{4} is kinetically facile at potentials above the equilibrium potential for the redox pair (0.23 V\textsubscript{SCE} shown in Fig. 3). However, since CO\textsubscript{2} is both insulating and insoluble, it will form a very thin outer layer on the oxide surface. It is unsurprising that its omission in the Co 2p band deconvolution was not a problem.

At 0.2 V\textsubscript{SCE}, the polarization resistance is initially low (~0.5 MΩ cm\textsuperscript{2}) at 2 h, but it increases steadily with time, reaching a value of ~2 MΩ cm\textsuperscript{2} after 30 h (Fig. 7). The rate of increase is slow in the first 10 h while the dominant anodic process is conversion of CoO/Co(OH)\textsubscript{2} to Co\textsubscript{3}O\textsubscript{4}. However, at longer times the resistance increases more rapidly due to the conversion of the CO\textsubscript{3}O\textsubscript{4} to more insulating and less soluble CO\textsubscript{3}O\textsubscript{4}. At the same time, the capacitance shows only slight decreases.

3.3.3. Stellite-6

3.3.3.1. Film growth at ~0.7 V\textsubscript{SCE}. At ~0.7 V\textsubscript{SCE}, the current behavior observed on Stellite-6 is very similar to that on Co (Fig. 11b); the current decreases nearly linearly with time and it switches from anodic to cathodic at ~300 s. The current during potentiostatic polarization on Stellite-6 is, however, about an order of magnitude lower than the current seen on Co under the same conditions. This is opposite to the current behavior observed during a CV scan; the current at ~0.7 V\textsubscript{SCE} is higher on Stellite-6 than on Co. The current observed at this potential during the CV scan corresponds to the oxidation of Co to Co\textsuperscript{III} to form cobalt chromite. During long-term polarization the conversion of the pre-existing thin layer of Co\textsuperscript{III} oxide to CoCr\textsubscript{2}O\textsubscript{4} is completed in a very short time and the current at longer times is due to anodic oxidation of Co to form a Co\textsuperscript{III} oxide/hydroxide layer. The current due to the latter anodic process is lower on Stellite-6 than on Co during at long times because of the presence of a passive inner layer of chromite on Stellite-6. Water reduction also occurs on Stellite-6 but the reduction current is lower than on Co because of the presence of the passivating chromite layer. Also less photocurrent is expected for Stellite-6. Cobalt chromite is also a p-type semiconductor but it has a higher band gap (3.4 eV) [24] than the band gap of Co(OH)\textsubscript{2} (2.4 eV).

The XPS analysis results for the Stellite-6 at ~0.7 V\textsubscript{SCE} (Fig. 10) show that Co\textsuperscript{III} is present mainly as cobalt chromite (CoCr\textsubscript{2}O\textsubscript{4})
and to a smaller extent as Co° oxide/hydroxide. The presence of Co° in the high resolution Co 2p band indicates that the film formed at −0.7 V SCE is very thin (<10 nm).

3.3.3.2. Film growth at −0.2 V SCE. The current at −0.2 V SCE shows a linear decrease with time (Fig. 11b). It reaches a very small value before the net current (~10⁻⁸ A cm⁻²) becomes cathodic after ~2 h. Since this cathodic current is very low, it could be generated by several contributing processes, all of which are slow. Potential contributors include water reduction and reduction of trace dissolved oxygen in the alloy, possibly assisted by photo-induced reactions. The oxidative conversion of the pre-existing chromium oxide layer to a cobalt chromite layer occurs early and the linear behavior of the current vs. time is attributed to steady growth of CoO/Co(OH)₂. The current at −0.2 V SCE is about an order of magnitude higher than the current at ~0.7 V SCE and this is consistent with the growth of a thicker outer layer of Co° oxide/hydroxide at this potential.

The XPS analysis results (Fig. 10) are also consistent with a thicker growth of CoO/Co(OH)₂ on an inner chromite layer. The XPS Co 2p spectrum is dominated by the CoO/Co(OH)₂ contribution for the films grown at ~0.2 V SCE (and ~0.1 V SCE which is also in potential region II) and the chromite contribution is below the XPS detection level. However, the metal Co° peak still contributes to the Co 2p band, indicating that the oxide layer is still thinner than 9 nm at this potential.

The EIS analysis of the film growth at ~0.2 V SCE (Fig. 7) shows that the polarization resistance is 2.0–2.5 MΩ cm² and relatively independent of time. This is consistent with the presence of a passivating chromite layer on Stellite-6. The resistance is already high at the time of the first EIS measurement (2 h) due to the presence of the chromite layer. The resistance increases only slightly with time (from 2.0 to 2.5 MΩ cm²) and the capacitance remains nearly constant at ~6 F cm⁻², which attests to the steady-state nature of the outer Co° oxide/hydroxide layer.

3.3.3.3. Film growth in potential range of 0.1–0.4 V SCE. Since the electrochemical reactivity of Stellite-6 is high at potentials >0.1 V SCE (Fig. 5b) and ECORR increases to a value greater than 0.1 V SCE when radiation is present (Fig. 2), the anodic oxidation and dissolution of Stellite-6 was explored at a number of potentials within potential regions III and IV. The potentiostatic polarization results are shown in Fig. 12. At all potentials >0.1 V SCE the current initially decreases nearly linearly with time. However, after times of about 10–100 s, the rate of current decrease slows and becomes nonlinear. The slowing of the current decrease occurs faster with higher applied potentials. This change in behavior indicated the presence of more than one anodic process. Candidates include metal cation dissolution or further oxidation of an oxide that has already formed. At 0.4 V SCE, the current on Stellite-6 reaches a constant, value after only ~10 s. The magnitude of this current (30 μA cm⁻²) approaches a value expected for an aqueous diffusion-limited process at the electrode surface. At this potential, oxidation of insoluble CrIV oxide to highly soluble CrV oxide species is allowed and the high steady-state current at long times is attributed to this oxidation and chromium dissolution. This explanation is consistent with a potential dependent rate for chromium oxidation.

The presence of CoOOH in films grown at potentials >0.1 V SCE was found by the XPS (Fig. 10a). The fraction of CoOOH in the outer layer increases, while the fraction of CoO/Co(OH)₂ decreases, with an increase in the applied potential. The ratio of Co/Cr in the surface oxide also increases in this potential region, consistent with the loss of Cr from the oxide surface. No metal component of the Co 2p band was found showing that the oxides grown in this potential region are thicker than 10 nm despite the high rate of Cr dissolution.

Comparison of the XPS results for Co and Stellite-6 (Figs. 9a and 10a) shows that the Co° species formed at potentials >0.1 V SCE on Stellite-6 is mainly CoOOH while it is mainly Co₃O₄ on Co. The presence of the chromite-like inner layer on Stellite-6 means that Co° reaches the oxide/water interface at a slower rate and all of this Co° can be subsequently oxidized to CoIV through the kinetically favored, formation of CoOOH. As discussed for reactions (5) and (6) in Section 3.2.1.1, the oxidation of Co(OH)₂ to CoOOH should be faster than the oxidation of Co(OH)₂ to Co₃O₄.

At 0.2 V SCE, the polarization resistances the Stellite-6 films are lower and the capacitances are higher than the corresponding values derived for films grown at ~0.2 V SCE. At 0.2 V SCE, the CrIII can begin to oxidize to CrVI, which is less protective, rendering the oxide film somewhat less protective, and decreasing it resistivity. The capacitance value (~150 μF cm⁻²) is independent of time and is an order of magnitude higher than that expected for a double-layer capacitance [13]. Since a potential of 0.2 V SCE is high enough to drive cobalt oxidation and since the oxide layer on Stellite-6 at this potential has a mix of metal cation oxidation states, any change in the relative population of species in each oxidation state would change the net surface charge. For example, the oxidation of Co° to CoIII can attract more OH⁻ to the oxide surface whereas the reduction of CoIII to Co° repels OH⁻. This is equivalent to adsorbing and desorbing a high surface coverage of ions and leads to the storage of a large amount of charge in an extremely thin layer in the interfacial region. This is often referred to as pseudo-capacitance and is the probable explanation for the observed high capacitance value [14].

4. Conclusions

At pH 10.6 and room temperature, gamma-irradiation at a dose rate of 5.5 kGy h⁻¹ increases the corrosion potential from ~0.7 V SCE to 0.08 V SCE on pure Co and from ~0.48 V SCE to 0.12 V SCE on Stellite-6. The corrosion behavior of Co and Stellite-6 can be divided into a number of potential regions and the presence of ionizing radiation shifts the corrosion potential from the transition between potential regions I and II to the transition between potential regions II and III for both metals. The transition from region I to II occurs near ~0.7 V SCE, the equilibrium potential for Co to CoO/Co(OH)₂ oxidation, while the transition from region II to III occurs at ~0.1 V SCE, the equilibrium potential for Co₀/Co(OH)₂ conversion to mixed Co°/CoIII or Co°/CoIV oxides/hydroxides.

Due to the presence of a thin, defective CrIII oxide layer on Stellite-6, the oxidation of Co to CoIII starts at a lower potential on Stellite-6 than on Co. The Co° produced at potentials lower than
−0.7 V_{SCE} is incorporated into the Cr^{III} oxide layer on Stellite-6 and forms cobalt chromite (CoCr_{2}O_{4}). The chromite layer on Stellite-6 also suppresses the electrochemical reactivity of this alloy at higher potentials. The same cobalt oxidation reactions occur on Stellite-6 as on Co, but at much slower rates for a given potential. Gamma-irradiation increases the corrosion potential of both metals to a range where the rate of oxidation of Co to Co^{III} increases. This Co^{III} can further oxidize to form less soluble Co^{IV} species. The competition of these two reactions (oxidation of Co to Co^{III} and oxidation of Co^{II} to Co^{III}) determines the net effect of gamma radiation on the rate of Co dissolution from Stellite-6. Solution pH and temperature have a strong influence on oxide solubilities. Additional work to investigate influence of these parameters on Stellite corrosion is currently underway.

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